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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







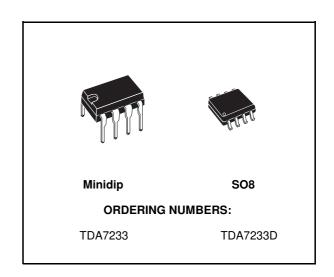


1W AUDIO AMPLIFIER WITH MUTE

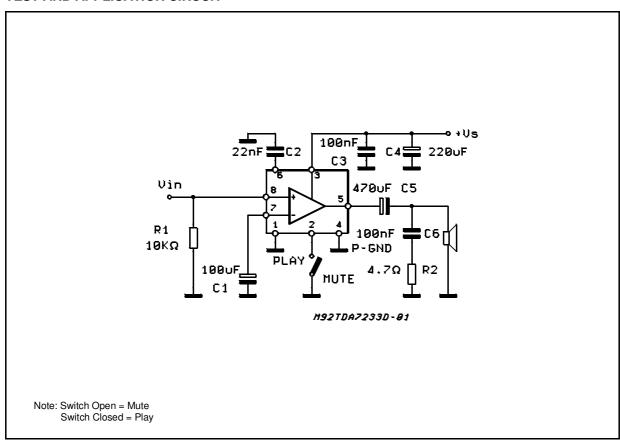
- OPERATING VOLTAGE 1.8 TO 15V
- EXTERNAL MUTE OR POWER DOWN FUNCTION
- IMPROVED SUPPLY VOLTAGE REJECTION
- LOW QUIESCENT CURRENT
- HIGH POWER CAPABILITY
- LOW CROSSOVER DISTORTION

DESCRIPTION

The TDA7233/D is a monolithic integrated circuit in 8 pin Minidip or SO8 package, intended for use as class AB power amplifier with a wide range of supply voltage from 1.8V to 15V in portable players, cordless telephones and Cellular Radios.



TEST AND APPLICATION CIRCUIT

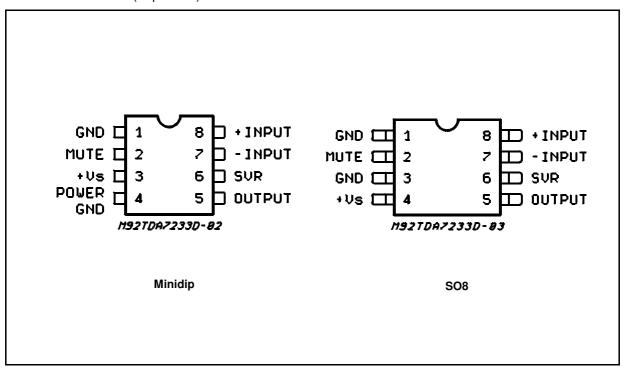


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ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
Vs	Supply Voltage	16	V
Io	Output Peak Current	1	Α
P _{tot}	Total Power Dissipation at T _{amb} = 50°C	1	W
T_{stg}, T_{j}	Storage and Junction Temperature	-40 to 150	°C

PIN CONNECTIONS (Top views)



THERMAL DATA

Symbol	Parameter	SO8	Minidip	Unit	
R _{th j-amb}	Thermal Resistance Junction-ambient	Max.	200	100	°C/W

ELECTRICAL CHARACTERISTICS ($V_s = 6 \text{ V}$, $T_{amb} = 25 \, ^{\circ}\text{C}$, unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Vs	Supply Voltage		1.8		15	V
Vo	Quiescent Out Voltage			2.7		V
		$V_s = 3 V$ $V_s = 9 V$		1.2 4.2		V
I _d	Quiescent Drain Current	MUTE HIGH		3.6	9	mA
-		MUTE LOW		0.4		
I _b	Input Bias Current			100		nA
Po	Output Power	$\begin{array}{l} d=10 \ \% & f=1 \ \text{KHz} \\ V_s=12 \ V & R_L=8 \ \Omega \\ V_s=9 \ V & R_L=4 \ \Omega \\ V_s=9 \ V & R_L=8 \ \Omega \\ V_s=6 \ V & R_L=8 \ \Omega \\ V_s=6 \ V & R_L=4 \ \Omega \\ V_s=3 \ V & R_L=4 \ \Omega \\ V_s=3 \ V & R_L=8 \ \Omega \\ \end{array}$		1.9 1.6 1 0.4 0.7 110 70		W W W W W mW
d	Distortion	$P_{o} = 0.5 \text{ W}$ f = 1 kHz $R_{L} = 8 \Omega$ $V_{s} = 9 \text{ V}$		0.3		%
G _v	Closed Loop Voltage Gain	f = 1 kHz		39		dB
R _{IN}	Input Resistance	f = 1 kHz	100			ΚΩ
e _N	Total Input Noise $(R_s = 10 \text{ k}\Omega)$	B = Curve A		2		μV
		B = 22 Hz to 22 kHz		3		
SVR	Supply Voltage Rejection	$f = 100 \text{ Hz}, R_g = 10 \text{ K}Ω$		45		dB
	MUTE Attenuation	V _o = 1 V f = 100 Hz to 10 kHz		70		dB
	MUTE Threshold			0.6		V
I _M	MUTE Current	V _S = 15V		0.4		mA

Figure 1: Output Power vs. Supply Voltage

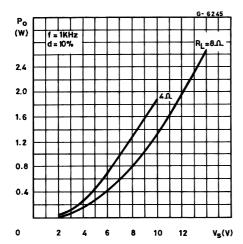


Figure 3: DC Output Voltage vs. Supply Voltage

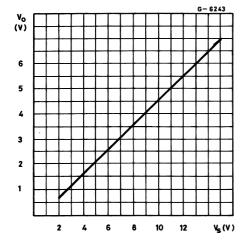


Figure 5: Total Dissipated Power vs. Supply Voltage

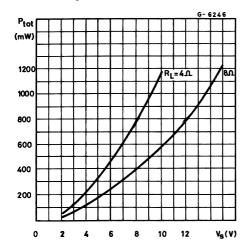


Figure 2: Supply Voltage Rejection vs. Frequency

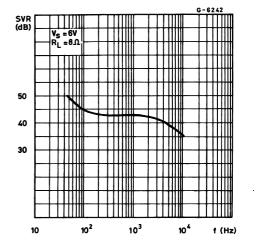
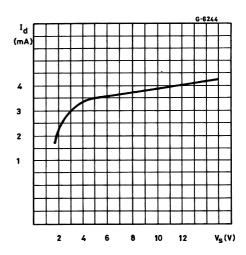


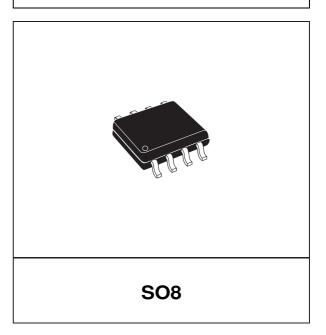
Figure 4: Quiescent Current vs. Supply Voltage

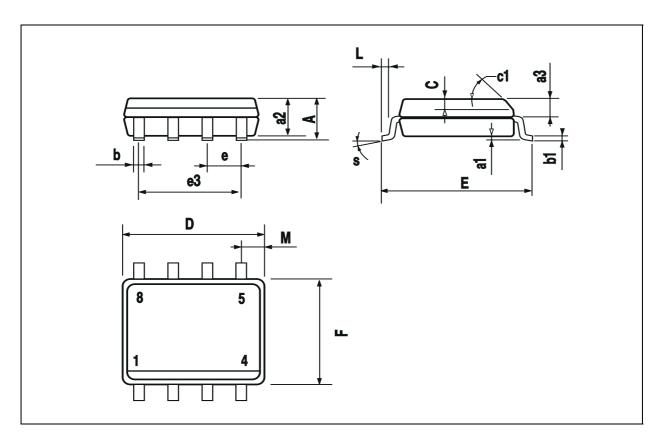


DIM.	mm			inch			
Dilvi.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Α			1.75			0.069	
a1	0.1		0.25	0.004		0.010	
a2			1.65			0.065	
аЗ	0.65		0.85	0.026		0.033	
b	0.35		0.48	0.014		0.019	
b1	0.19		0.25	0.007		0.010	
С	0.25		0.5	0.010		0.020	
c1			45° ((typ.)			
D (1)	4.8		5.0	0.189		0.197	
Е	5.8		6.2	0.228		0.244	
е		1.27			0.050		
еЗ		3.81			0.150		
F (1)	3.8		4.0	0.15		0.157	
L	0.4		1.27	0.016		0.050	
М			0.6			0.024	
S	8° (max.)						

(1) D and F do not include mold flash or protrusions. Mold flash or potrusions shall not exceed 0.15mm (.006inch).

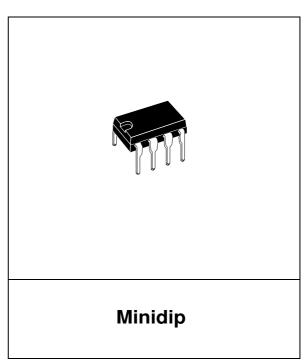
OUTLINE AND MECHANICAL DATA

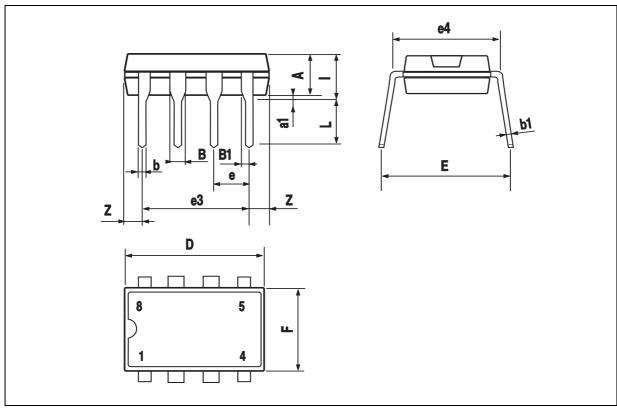




DIM.	mm			inch			
DIM.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Α		3.32			0.131		
a1	0.51			0.020			
В	1.15		1.65	0.045		0.065	
b	0.356		0.55	0.014		0.022	
b1	0.204		0.304	0.008		0.012	
D			10.92			0.430	
E	7.95		9.75	0.313		0.384	
е		2.54			0.100		
e3		7.62			0.300		
e4		7.62			0.300		
F			6.6			0.260	
I			5.08			0.200	
L	3.18		3.81	0.125		0.150	
Z			1.52			0.060	

OUTLINE AND MECHANICAL DATA





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